



## High Efficiency Fast Response 8A Continuous, 16A Peak, 28V Input Synchronous Step Down Regulator

### General Description

The SY8368L is a high-efficiency synchronous step-down DC/DC regulator featuring internal power and synchronous rectifier switches capable of delivering 8A of continuous output current and up to 16A peak output current over a wide input voltage ranging from 4.5V to 28V.

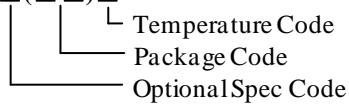
Silergy's proprietary Instant-PWM™ fast-response, constant-on-time (COT) PWM control method supports high input/output voltage ratios (low duty cycles), and fast transient response while maintaining a near constant operating frequency over line, load and output voltage ranges. This control method provides stable operation without complex compensation and even with low ESR ceramic capacitors.

Internal 20mΩ power and 10mΩ synchronous rectifier switches provide excellent efficiency over a range of applications, especially for low output voltages and low duty cycles. Cycle-by-cycle current limit, input under voltage lock-out, internal soft-start, output under and over voltage protection, and over temperature protection provide safe operation in all operating conditions.

The SY8368L is available in a compact QFN3×3-12 package.

### Ordering Information

SY8368 □(□□)□



Ordering Number	Package type	Note
SY8368LQQC	QFN3×3-12	--

### Features

- Fast Transient Response
- Wide Input Voltage Range: 4.5-28V
- Low  $R_{DS(ON)}$  for Internal Switches (Top FET/Bottom FET) :20mΩ/10mΩ
- 8A Continuous/16A Peak Output Current Capability
- Accurate Feedback Reference Voltage: 0.6V  $\pm 1\%$
- Pseudo-constant 500kHz Operating Frequency
- Internal 600μs Soft-start Limits Inrush Current
- PSM/FCCM Selectable Light Load Operation Mode
- Power Good Indicator
- Cycle-by-Cycle Current Limit
- Latch Off Mode Output Under Voltage and Over Voltage Protection
- Over Temperature Protection with Auto Recovery
- Compact Package: QFN3×3-12

### Applications

- LCD-TV/Net-TV/3DTV
- Set Top Box
- Notebook
- High Power AP

## Typical Applications

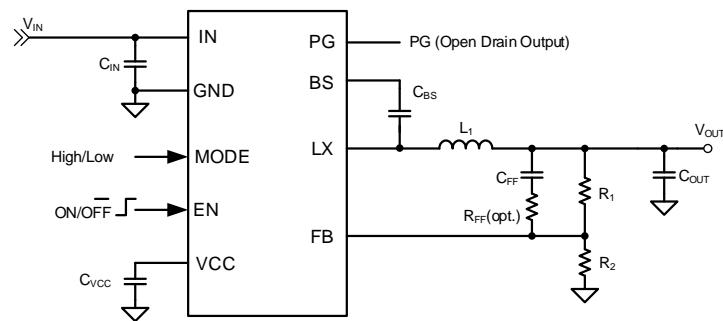


Figure1. Schematic

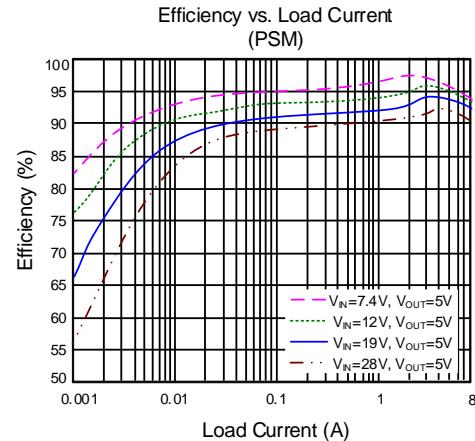
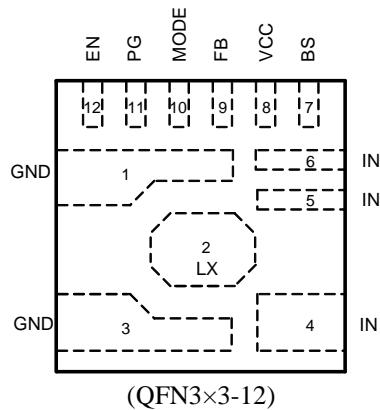


Figure2. Efficiency

## Pinout (top view)



Top Mark: BQHxyz, (Device code: BQH, x=year code, y=week code, z= lot number code)

Pin Name	Pin Number	Pin Description
GND	1,3	Ground pin
LX	2	Inductor pin. Connect this pin to the switching node of inductor
IN	4,5,6	Input pin. Decouple this pin to GND pin with at least 10 $\mu$ F ceramic cap
BS	7	Boot-Strap pin. Supply high side gate driver. Decouple this pin to LX pin with 0.1 $\mu$ F ceramic cap.
VCC	8	Internal 3.3V LDO output. Power supply for internal analog circuits and driving circuit. Bypass this pin to GND with a 2.2 $\mu$ F ceramic capacitor..
FB	9	Output feedback pin. Connect this pin to the center point of the output resistor divider (as shown in Figure 1) to program the output voltage: $V_{SET}=0.6\times(1+R_1/R_2)$
MODE	10	Light load operation mode selection pin. Pull this pin low for PSM operation, and pull this pin high for FCCM operation. Do not leave this pin floating.
PG	11	Power good indicator. Open drain output when the output voltage is within 92.5% to 120% of regulation point.
EN	12	Enable control. Pull this pin high to enable the IC. Do not leave this pin floating.

## Block Diagram

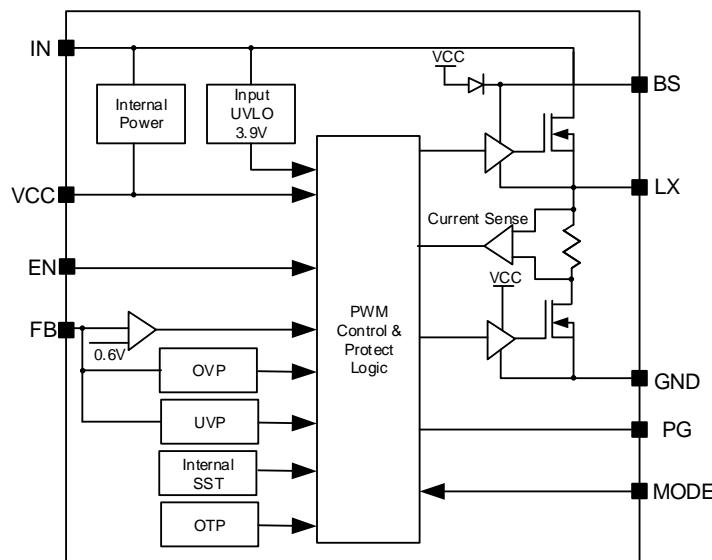


Figure3. Block Diagram

### Absolute Maximum Ratings (Note 1)

IN, LX, PG, EN -----	30V
BS-LX, FB, MODE, VCC-----	4V
Maximum Power Dissipation, $P_{D,MAX}$ @ $T_A = 25^\circ\text{C}$ QFN3x3-12	3.33W
Package Thermal Resistance (Note 2)	
$\theta_{JA}$ -----	30°C/W
$\theta_{JC}$ -----	4°C/W
Junction Temperature Range -----	150°C
Lead Temperature (Soldering, 10 sec.) -----	260°C
Storage Temperature Range -----	-65°C to 150°C
Dynamic LX voltage in 50ns duration -----	IN+3V to GND-4V

### Recommended Operating Conditions (Note 3)

Supply Input Voltage -----	4.5V to 28V
Junction Temperature Range -----	-40°C to 125°C
Ambient Temperature Range -----	-40°C to 85°C

## Electrical Characteristics

( $V_{IN} = 12V$ ,  $V_{OUT} = 5V$ ,  $C_{OUT} = 100\mu F$ ,  $T_A = 25^\circ C$ ,  $I_{OUT} = 2A$ , unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Input Voltage Range	$V_{IN}$		4.5		28	V
Quiescent Current	$I_Q$	$EN=1, I_{OUT}=0, MODE=Low, V_{OUT}=V_{SET}\times 105\%$		100		$\mu A$
Shutdown Current	$I_{SHDN}$	$EN=0$		6	10	$\mu A$
Feedback Reference Voltage	$V_{REF}$		0.594	0.6	0.606	V
FB Input Current	$I_{FB}$	$V_{FB}=4V$	-50		50	nA
Top FET $R_{DS(ON)}$	$R_{DS(ON)1}$			20		$m\Omega$
Bottom FET $R_{DS(ON)}$	$R_{DS(ON)2}$			10		$m\Omega$
Bottom FET Current Limit	$I_{LIM,BOT}$		12			A
Bottom FET Reverse Current Limit	$I_{LMT,RVS}$			-2.75		A
Soft-start Time	$t_{SS}$	$V_{OUT}$ from 0% to 100% $V_{SET}$		600		$\mu s$
EN/MODE Input Voltage High	$V_{EN,H}$		1.0			V
EN/MODE Input Voltage Low	$V_{EN,L}$				0.4	V
EN Leakage Current	$I_{EN}$		-1		1	$\mu A$
MODE Leakage Current	$I_{MODE}$		-1		1	$\mu A$
Input UVLO Threshold	$V_{UVLO}$				3.9	V
Input UVLO Hysteresis	$V_{HYS}$			0.3		V
Switching Frequency	$F_{SW}$	$V_{OUT}=5V, CCM$	425	500	575	kHz
Min ON Time	$t_{ON,MIN}$	$V_{IN}=V_{IN,MAX}$		50		ns
Min OFF Time	$t_{OFF,MIN}$			180		ns
VCC Output Voltage	$V_{CC}$	VCC with 1mA load	3.2	3.3	3.45	V
Output Under Voltage Threshold	$V_{UVP}$	$V_{FB}$ falling		33.3		% $V_{REF}$
Output UVP Delay Time	$t_{UVP,DLY}$			10		$\mu s$
Output Over Voltage Threshold	$V_{OVP}$	$V_{FB}$ rising		120		% $V_{REF}$
Output OVP Delay Time	$t_{OVP,DLY}$			12		$\mu s$
Power Good Threshold	$V_{PG}$	$V_{FB}$ rising (good)		92.5		% $V_{REF}$
Power Good Hysteresis	$V_{PG,HYS}$			2		% $V_{REF}$
Power Good Delay Time	$t_{PG,R}$			2.5		$\mu s$
	$t_{PG,F}$			15		$\mu s$
Thermal Shutdown Temperature	$T_{SD}$			150		$^\circ C$
Thermal Shutdown Hysteresis	$THYS$			15		$^\circ C$

**Note 1:** Stresses beyond the “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability

**Note 2:** Package thermal resistance is measured in the natural convection at  $T_A = 25^\circ C$  on a four-layer Silergy Evaluation Board.

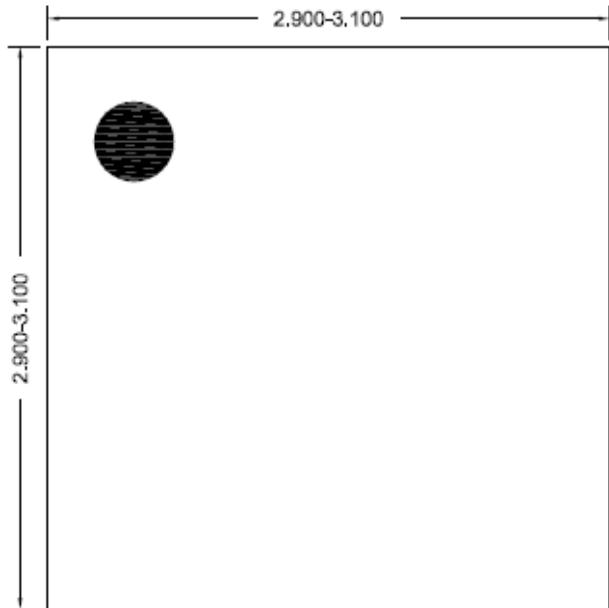
**Note 3:** The device is not guaranteed to function outside its operating conditions.



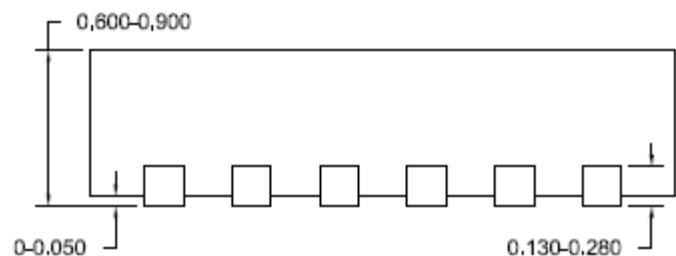
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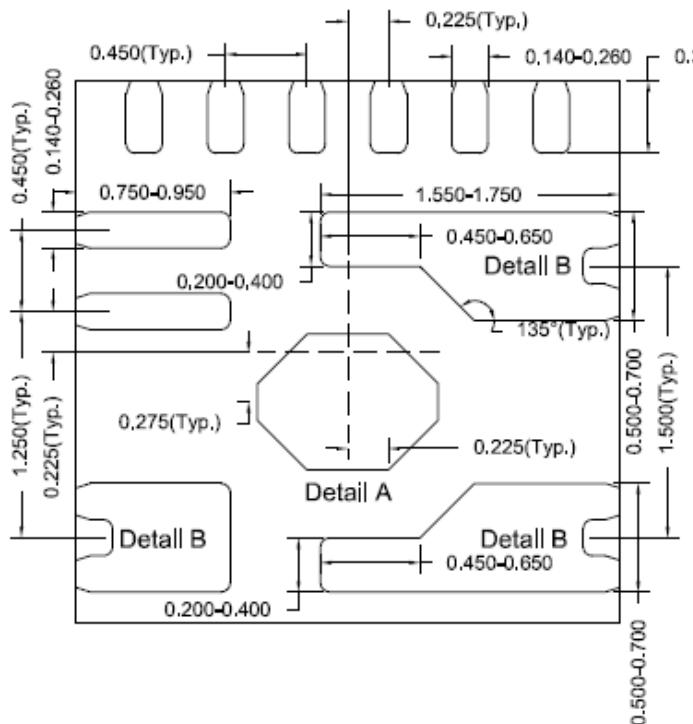
## QFN3x3-12 Package Outline Drawing



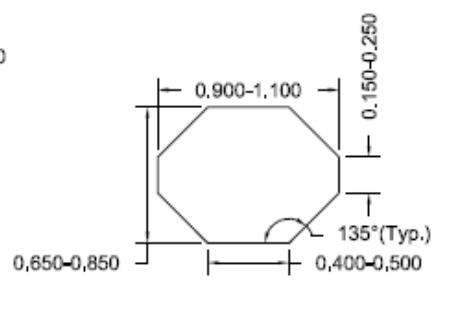
Top View



Side View



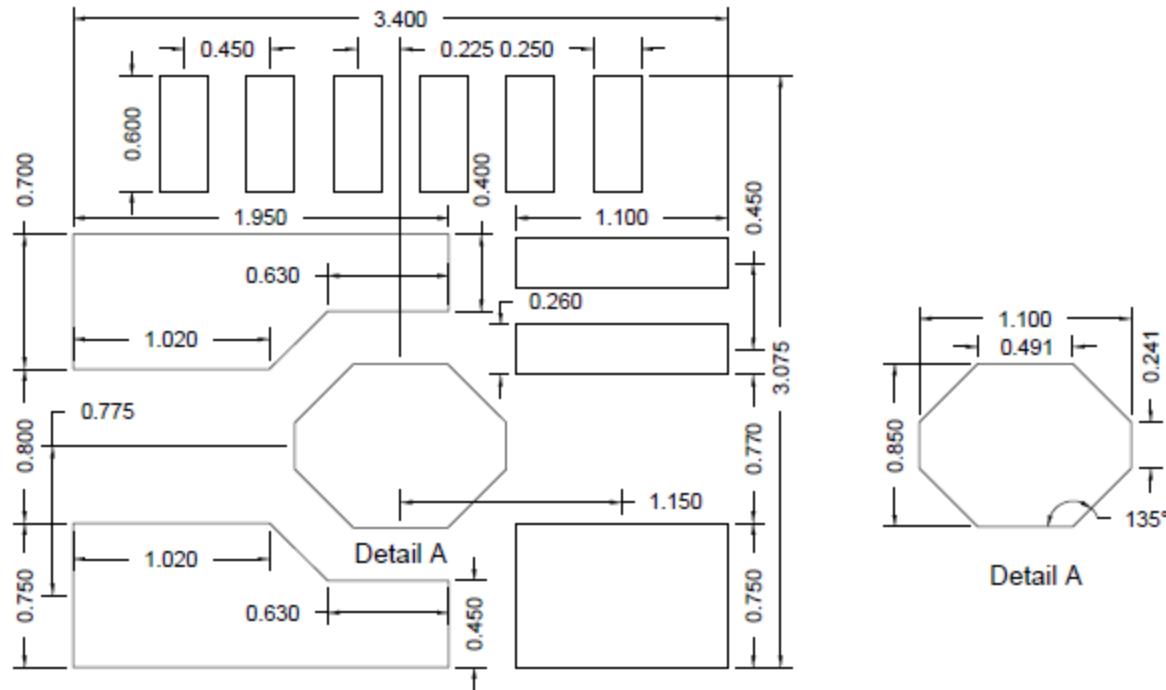
Bottom View



Detail A



Detail B



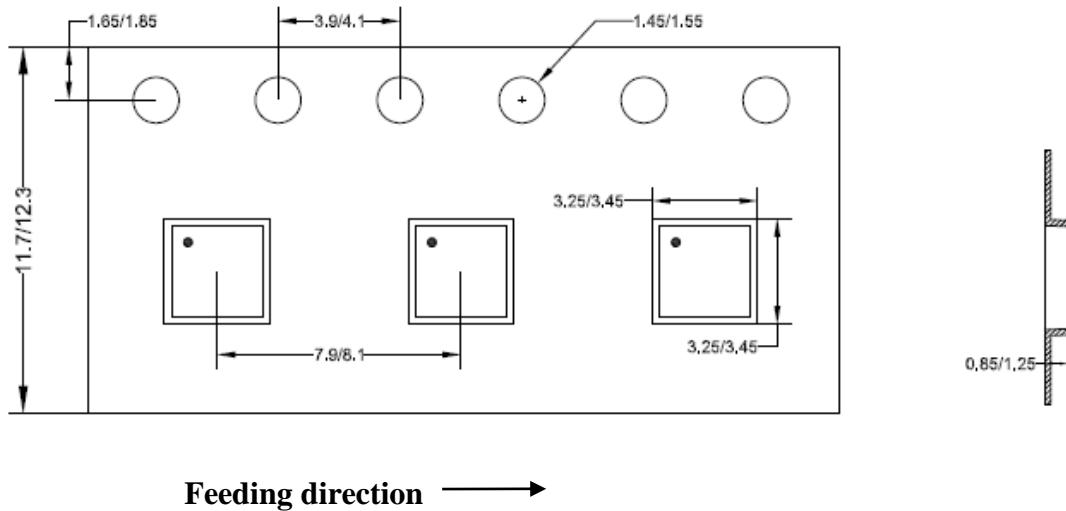
**Recommended PCB layout  
(Reference Only)**

**Notes:** All dimension in millimeter and exclude mold flash & metal burr.

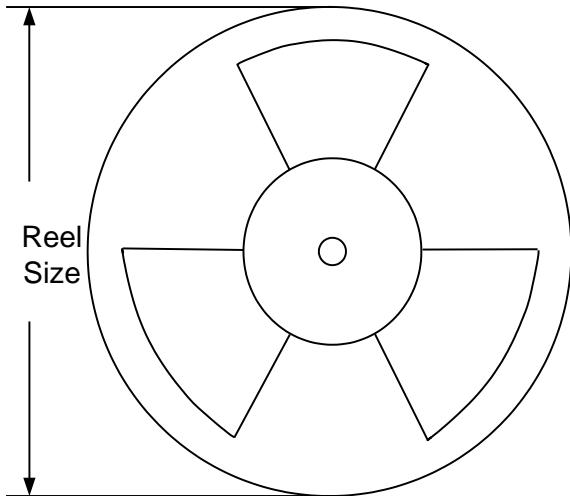
## Taping & Reel Specification

### 1. Taping orientation

QFN3x3



### 2. Carrier Tape & Reel specification for packages



Package types	Tape width (mm)	Pocket pitch(mm)	Reel size (Inch)	Trailer length(mm)	Leader length (mm)	Qty per reel
QFN3x3	12	8	13"	400	400	5000

### 3. Others: NA